The influence of alloying elements on the electrochemical and semiconducting properties of thin passive films formed on several steels (carbon steel, ferritic and austenitic stainless steels) has been studied in a highly concentrated lithium bromide (LiBr) solution at 25°C, by means of potentiodynamic tests and Mott-Schottky analysis. The addition of Cr to carbon steel promoted the formation of a p-type semiconducting region in the passive film. A high Ni content modified the electronic behaviour of highly alloyed austenitic stainless steels. Mo did not modify the electronic structure of the passive films, but reduced the concentration of defects.

**Keywords:** Carbon steel; stainless steel; thin passive films; semiconducting properties; Mott-Schottky.
1. INTRODUCTION

Stainless steels are the most widely known metallic materials, and their demand has increased dramatically in recent years [1-3]. Stainless steels owe their widespread use to a combination of unique properties that have advantage over those of other steels and nonferrous metals for many applications. The main characteristics are their resistance to corrosion in different environments, their good mechanical properties over an extremely wide range of temperatures, and their resistance to oxidation and scaling at very high temperatures [1, 3]. The corrosion resistance of stainless steels is provided by a very thin and protective surface oxide film, known as passive film. It is generally accepted that passive films formed on stainless steels have a duplex structure which consists of an inner region rich in chromium and an outer region rich in iron [4-9]. Some authors have also observed that when the amount of molybdenum in a stainless steel is high enough, it is incorporated into the passive film, showing complex oxide chemistry with different states of oxidation [7, 10, 11]. Depending on the nickel content in the stainless steel, Ni may or may not appear in the chromium and iron oxide layers [8, 9].

One of the main factors that control the behaviour of a passive film is its electronic properties [4-6, 12-22]. However, there is some controversy as to the electronic structure of the layers which make up the passive films formed on stainless steels, especially on those with high Ni content, and no general agreement exists on this topic yet. Some studies that used Mott-Schottky analysis [18, 19, 23-26] claimed that passive films formed on stainless steels are \textit{n}-type semiconductors due to a protective barrier layer of \textit{Cr}_2\text{O}_3; however, it is interesting to note that in the references mentioned above, only limited information has been obtained, since capacitance measurements have been
generally restricted to the more anodic potential range. According to Sato [12, 21], the passive film comprises an anion-selective and n-type semiconductive inner layer, and a cation-selective and p-type semiconductive outer layer. In other studies [4-6, 17, 27, 28] the electronic structure of passive films formed on stainless steels has been described as a p-type inner layer (rich in Cr-species) and an n-type outer layer (rich in Fe-species).

Highly concentrated aqueous LiBr solutions are widely used as a refrigerant for absorption-type air-conditioning and industrial drying systems due to its good thermodynamic properties [29-32], but these solutions are highly corrosive and attack the copper and ferrous (austenitic and duplex stainless steels) parts of the system [33-40]. Stainless steels are susceptible to several forms of localised corrosive attack, especially in the presence of halides, such as bromides. The general and localised corrosion behaviour of passive films can be related to their semiconducting properties, so it is essential to understand these semiconducting properties to correlate them with the corrosion behaviour of stainless steels. However, the interpretation of the electronic properties of passive films formed on stainless steels is difficult because of the complexity of the bilayer structure of the films. Since the alloying elements can modify the semiconducting behaviour of the different oxide layers, their influence must be taken into account when studying passive films semiconductivity, especially in highly alloyed materials.

In the present work, the influence of alloying elements on the semiconducting properties of passive films formed on several steels (carbon and stainless steels) has been studied in a highly concentrated LiBr solution (992 g/l, commonly used in absorption machines) at 25° C, by means of Mott-Schottky analysis. Potentiodynamic polarisation
experiments have also been carried out to establish a connection between the electrochemical and electronic behaviours.

2. EXPERIMENTAL DETAILS

2.1. Materials, solution and electrochemical cell

Experiments were performed in a deaerated and highly concentrated LiBr solution (992 g/l, 11.42 M), at 25º C. The deaerated atmosphere was created by bubbling N₂ in the solution for 1 hour before the tests, and over the electrolyte solution during the tests.

The materials tested were different steels (carbon and stainless steels), with variable Cr, Ni and Mo content (Table 1). The electrodes were cylindrically shaped (8-mm in diameter and 55 mm long) and covered with a polytetrafluoroethylene coating. The area exposed to the solution was 0.5 cm². All specimens were wet abraded from 500 to 4000 SiC grit, and finally cleaned with ethanol, rinsed with distilled water and air-dried.

The electrochemical measurements were carried out with an Autolab PGSTAT302N potentiostat. An Ag/AgCl (3M KCl) electrode served as the reference electrode and a platinum wire served as the counter electrode. In all cases the tests were repeated at least three times in order to verify reproducibility.

2.2. Potentiodynamic polarisation tests
Potentiodynamic polarisation tests began at a potential value of -250 mV with respect to the open circuit potential and the potential was subsequently scanned anodically at 0.5 mV s\(^{-1}\) until the current density reached 1 mA/cm\(^2\). The pitting potential \((E_p)\) has been defined as the potential at which current density reaches a value of 100 µA/cm\(^2\) [40-42].

2.3. Capacitance measurements

Before passivation, the electrode potential was kept at a cathodic value of -800 mV\(_{\text{Ag/AgCl}}\) for 15 minutes, to create reproducible initial conditions. Afterwards, the working electrodes were polarised at the film formation potentials of -300 mV\(_{\text{Ag/AgCl}}\) for 1 hour. A film formation potential of 100 mV\(_{\text{Ag/AgCl}}\) was also used in the case of Alloy 33 and Alloy 31. Capacitance measurements were performed once a stable passive film was formed on the surface of the samples. The capacitance of the interface was calculated at a constant frequency of 5 kHz using a 10 mV amplitude signal and scanning the potential from the formation value in the negative direction at a rate of 50 mV s\(^{-1}\). A high scanning rate was used to avoid electroreduction of the passive film and changes in film thickness during the measurements. At a sufficiently high scanning rate, the defect structure within the passive film is “frozen-in”, which avoids the defect density from being affected by potential [43-45].

3. RESULTS AND DISCUSSION

3.1. Potentiodynamic polarisation curves
Figure 1 shows the potentiodynamic polarisation curves for the six steels studied in the 992 g/l LiBr solution at 25º C. As tests were reproducible, the curves illustrate one of the recorded measurements. A passive region where current density is almost constant is observed in all the curves. Polarisation curves also show that, once the pitting potential is reached, the current density increases sharply. The standard electrode potential of the pair Br₂/Br⁻ (E₀ = 882 mV Ag/AgCl) is higher than the potential values at which current density increases abruptly, so this increase indicates the breakdown of the passive film. Moreover, visual inspection of the electrodes after the potentiodynamic tests revealed clear pits throughout the samples surface.

Before the sharp increase in current density due to the onset of pitting corrosion, a slight increase in current density can be observed in the potentiodynamic polarisation curves of the different stainless steels. This steady increase of current density can be associated with the transpassive dissolution of Cr-containing species and is closely related to the passive film breakdown and localised corrosion phenomena [22].

Carbon steel S355J2G3 presents the highest values of current density within the passive region, as well as the lowest pitting potential, Eₚ. This displacement of the pitting potential towards more negative values makes the extent of the passive region be significantly lower for the carbon steel than for the stainless steels.

The curves of stainless steels show lower passive current densities compared with the values recorded for the carbon steel, due to the influence of Cr [33]. The main difference between the curves of the different stainless steels is the value of the pitting potential. The value of the pitting potential is affected by several parameters, such as
temperature, concentration of aggressive ions or alloy composition. In this case, the differences in $E_p$ between stainless steels are caused by the alloying elements. When alloying the carbon steel with 17 wt.% Cr (AISI 430), the pitting potential increases dramatically. Therefore, the positive influence of Cr on the pitting corrosion resistance of stainless steels is evident from Figure 1, due to the formation of Cr(III) oxides and hydroxides. The addition of 10 wt.% Ni (AISI 304) modifies the value of $E_p$ to some extent, whereas the addition of 2.3 wt.% Mo (AISI 316) has a more clear influence. Finally, a considerable increase in Cr and Ni content (Alloy 33) as well as in Mo content (Alloy 31) enhances the resistance to pitting corrosion even more. The main influence of Ni in the curves shown in Figure 1 is the reduction of the passive current density, which decreases for AISI 304 if compared with AISI 430. It can also be observed that Mo enhances the passivity of AISI 316 in comparison with AISI 304, and Alloy 31 in comparison with Alloy 33, shifting the pitting potential towards more positive values, having therefore a beneficial influence on the pitting resistance of stainless steels, as also reported by other authors [10, 36, 46-48].

The relative resistance of a stainless steel to pitting corrosion in the presence of aggressive anions, such as bromides, can be related to an alloy composition by an empirical formula called the Pitting Resistance Equivalent Number (PREN). The most commonly used PREN expression is [49]:

$$\text{PREN} = \%\text{Cr} + 3.3\left[\%\text{Mo} + 0.5\%\text{W}\right] + x \cdot \%\text{N}$$  \hspace{1cm} (1)
where the multiplier $x$ is typically given as 30, and composition is weight percent. In general, the larger the numerical value of PREN, the higher the pitting corrosion resistance.

**Table 2** shows the values of the pitting potential, $E_p$, and PREN for the six steels studied in this work. It can be seen that $E_p$ increases with increasing PREN values. A PREN value of 33 or higher is considered necessary for pitting resistance to aggressive environments, such as seawater [2].

### 3.2. Capacitance measurements

Oxide films with perfect crystal structures can be considered as insulators provided they are stoichiometric. However, the presence of point defects in the structure of passive films makes these oxide films behave as extrinsic semiconductors when exposed to an aqueous solution. The main point defects are cation vacancies ($V_M^{\chi}$), anion vacancies (oxygen vacancies, $V_O^{\chi}$) and/or cation interstitials, $M_i^{\chi}$. Kroger-Vink notation is used for the effective positive (\(\cdot\)) and negative (\(\chi\)) charges in oxygen and cation vacancies, respectively. The extrinsic semiconducting behaviour of these passive films can be $n$-type and/or $p$-type, depending on the relative number of defects within the film [17, 18, 26, 28, 50-55]. Thus, a predominance of cation vacancies over oxygen vacancies and/or cation interstitials leads to $p$-type semiconductivity, while the opposite situation leads to $n$-type semiconductivity.

The capacitance of the passive film/electrolyte interface, $C$, can be described by a Mott-Schottky relationship. Taking into account the capacitance of the Helmholtz layer and
neglecting the Guoy-Chapman diffuse layer and surface states contribution for the total capacitance, this relationship becomes [4, 22]:

\[
\frac{1}{C^2} = \frac{1}{C_{SC}^2} + \frac{1}{C_H^2} + \frac{2}{C_{SC}C_H} \quad (2)
\]

where \( C_{SC} \) is the capacitance of the space charge layer and \( C_H \) the capacitance of the Helmholtz layer. Eq. (2) can be expanded to distinguish between \( n \)-type and \( p \)-type semiconductors:

\[
\frac{1}{C^2} = \frac{1}{C_H^2} + \frac{2}{\varepsilon \varepsilon_0 e N_D} \left( E - E_{FB} - \frac{kT}{e} \right) \quad \text{\( n \)-type (3a)}
\]

\[
\frac{1}{C^2} = \frac{1}{C_H^2} - \frac{2}{\varepsilon \varepsilon_0 e N_A} \left( E - E_{FB} - \frac{kT}{e} \right) \quad \text{\( p \)-type (3b)}
\]

where \( \varepsilon \) represents the dielectric constant of the passive film (values of 12 [56, 57] and 15.6 [4, 5, 13] have been assumed for the oxides formed on carbon steel and stainless steels, respectively), \( \varepsilon_0 \) is the vacuum permittivity \((8.85 \cdot 10^{-14} \text{ F/cm})\), \( e \) is the electron charge \((1.60 \cdot 10^{-19} \text{ C})\), \( N_D \) and \( N_A \) are the donor and acceptor densities, respectively, \( E_{FB} \) is the flat-band potential, \( k \) is the Boltzmann constant \((1.38 \cdot 10^{-23} \text{ J/K})\) and \( T \) is the absolute temperature.

As it has been mentioned in the experimental procedure section, capacitance measurements were performed at 5 kHz, since it has been demonstrated in a previous work [22] that capacitance becomes independent of frequency at approximately 5 kHz.
for stainless steels in heavy brine LiBr solutions. Figure 2a shows the Mott-Schottky plots for the films formed on the six steels at the passive potential of -300 mV. To better observe the Mott-Schottky plots, Figure 2b shows the $C^2$ vs. $E$ representations for the steels with lower alloy element content (carbon steel, AISI 430, AISI 304 and AISI 316). Figure 2c shows the Mott-Schottky plots of Alloy 33 and Alloy 31 obtained at two different passive potentials: -300 and 100 mV. In general, plots reveal the presence of two linear regions at low and high potentials. In the region at $E > -0.65$ V, approximately, straight lines with positive slopes can be observed, indicating that capacitance represents the electrochemical behaviour of an $n$-type semiconductor, according to eq. (3a). In the more cathodic region ($E < -0.65$ V, approximately), there are straight lines with negative slopes, so the capacitance describes the behaviour of a $p$-type semiconductor, according to eq. (3b).

The values of the density of defects (donor and acceptor species, $N_D$ and $N_A$, respectively) within the passive films formed on the six steels at a given potential can be calculated from the positive and negative slopes of the linear zones in Mott-Schottky plots (Figure 2), using equations (3a) and (3b), respectively. Table 3 shows the values of $N_D$ and $N_A$ at film formation potentials of -300 mV and 100 mV (the latter only for Alloys 33 and 31).

3.2.1. Carbon steel

Carbon steel S355J2G3 does not present $p$-type semiconductivity since only one linear region with positive slope can be observed in Figure 2b, indicating an $n$-type semiconducting behaviour. Passive films formed on carbon steels have a similar
composition than those formed on iron with an inverse spinel structure related to both \( \gamma \)-\( \text{Fe}_2\text{O}_3 \) and \( \text{Fe}_3\text{O}_4 \) [56-59]. Thermodynamically, \( \text{Fe}_2\text{O}_3 \) is the most stable species at the experimental conditions [33] and the capacitance behaviour would be controlled by the electronic structure of \( \text{Fe}_2\text{O}_3 \) in the passive film, which explains the presence of the straight line with positive slope in the Mott-Schottky plot. In \( n \)-type semiconducting passive films, the predominant donor species are oxygen vacancies, \( V_0^{\bullet\bullet} \) and/or cation interstitials, \( \text{Fe}^{\chi^+}_i \).

At -300 mV, \( N_D \) is very high for the carbon steel (Table 3), which indicates a highly disordered nature of its passive film and low protective properties in concentrated LiBr media.

3.2.2. AISI 430, 304 and 316

The influence of chromium on the capacitance behaviour of stainless steels can be determined by observing the Mott-Schottky plot for AISI 430 (Figura 2b). This plot reveals the existence of two straight lines below and above a potential of about -0.65 V (the flat-band potential, \( E_{FB} \)). Thus, the addition of 17 wt.% Cr to carbon steel promotes the formation of a \( p \)-type semiconductivity region in the passive film. This \( p \)-type region can also be observed in the Mott-Schottky plots for AISI 304 and AISI 316. Many analytical studies [4-9] have revealed that passive films formed on stainless steels have, at least, a duplex structure which consists of an inner region rich in Cr and an outer layer rich in Fe. The significant enrichment of chromium species within the inner layer of the passive film can be explained by the preferential oxidation of Cr prior to the onset of Fe oxidation [60]. Besides, the location of each alloying component within the
passive film depends on their mobility through the film [60, 61]. Therefore, faster
diffusing components will pass through to the outer layer, such as Fe cations, while
slower diffusing components like Cr cations will be oxidized without movement and
remain in the inner region of the passive film. Therefore, the \( p \)-type region observed in

**Figure 2b** for the three stainless steels with 17-18 wt.% Cr seems to be related to the
inner layer of the passive film, while the \( n \)-type could be attributed to the
electrochemical behaviour of the outer layer.

The bilayer structure of passive films formed on stainless steels has shown to be more
complex [8, 10, 14, 17, 27, 62, 63]. In ferritic and austenitic stainless steels with less
than 10-12 wt.% Ni, the outer region of the passive film is made up of a layer of Cr and
Fe hydroxides, oxy-hydroxides and \( \text{Fe}_2\text{O}_3 \) [14], with \( n \)-type semiconductivity [63, 64].
The hydroxides and oxy-hydroxides present in the outer layer of the film form via
precipitation from hydrolysis of metal cations and can incorporate other species from
solution (e.g. \( \text{Br}^- \)) [50, 52, 53, 65]. The inner layer consists of an oxide Fe-Cr spinel
whose general structure can be written as \( \text{Fe}^{\text{II}}[\text{Cr}^{\text{III}}]_x\text{Fe}^{\text{III}}(1-x)_2\text{O}_4 \), where \( 0 < x \leq 1 \)
[14]. Normal spinels, such as \( \text{FeCr}_2\text{O}_4 \), have the general formula \( \text{AB}_2\text{O}_4 \), where the
divalent A-cations are occupying 1/8 of the tetrahedral holes and the trivalent B-cations
are occupying 1/2 of the octahedral holes. In inverse spinels, which have the general
formula \( \text{B}[\text{AB}]\text{O}_4 \), the trivalent B-cations are occupying 1/8 of the tetrahedral holes and
the second divalent B- and trivalent A-cations are occupying 1/2 of the octahedral holes.

It has been observed [14] that the mixed Fe-Cr oxide with spinel structure can act as
both an \( n \)-type and a \( p \)-type semiconductor due to the influence of different donor and
acceptor species, respectively. Making \( x = 1 \), the general formula of the spinel can be
simplified as FeCr$_2$O$_4$ (chromite, with the tetrahedral and octahedral sites occupied by Fe(II) and Cr(III) cations, respectively), which is known to have deficiency of cations [66] and, therefore, behaves as a $p$-type semiconductor [63, 66]. On the other hand, with $x \to 0$, the formula of the spinel approaches that of Fe$_3$O$_4$ (magnetite, which is an inverse spinel where all the Fe(II) cations occupy the octahedral sites and Fe(III) cations occupy tetrahedral and octahedral sites evenly). Inverse spinels, such as Fe$_3$O$_4$, NiFe$_2$O$_4$ or MgFe$_2$O$_4$, are normally $n$-type semiconductors [66, 67]. Therefore, an increase of Cr(III) in the spinel structure will favour $p$-type semiconductivity. As mentioned above, it is widely accepted that there is an enrichment of Cr in the inner region of passive films formed on stainless steels [4-9], accordingly the $p$-type region observed in Figure 2b should be related to the inner part of the passive film close to the metal surface. According to the previous explanations and the capacitance results, the passive film formed on AISI 430 consists of an inner layer of anhydrous mixed Fe-Cr oxide with a spinel structure which behaves as a $p$-type semiconductor (rich in Cr) in the region close to the metal surface and as an $n$-type semiconductor (rich in Fe) in the region close to the outer layer of the film. This outer layer is made up of Cr and Fe hydroxides, oxy-hydroxides and Fe$_2$O$_3$ with $n$-type semiconducting behaviour.

Regarding the influence of Ni on the semiconducting behaviour of AISI 304 and AISI 316, some authors have reported [7, 8, 68, 69] that the Ni content of the passive film formed on conventional austenitic stainless steels was very low or non-existent. It can be observed in Figure 2b that the capacitance behaviour of AISI 430 and AISI 304 is very similar, as well as the values of $N_A$ and $N_D$ (Table 3). Thus, the Mott-Schottky plot of AISI 304 shows the behaviour of the bilayer passive film described previously for AISI 430.
The addition of 2.3 wt.% Mo does not modify the electronic structure of the passive film formed on AISI 316 (Figure 2b), although it has a positive influence, decreasing the capacitance values, especially in the $n$-type region. For AISI 316, the value of $N_A$ remains almost constant but $N_D$ decreased with respect to the values obtained for AISI 430 and 304 (Table 3). The decrease in donor density has been observed in the literature when alloying austenitic stainless steels with Mo [6, 48, 70]. Mo(VI) has been found to be enriched at the surface of the passive film [10, 11], whereas Mo(IV) species are distributed more homogeneously through the film [10] or associated with the inner layer [11]. The positive sign of oxygen vacancies and/or cation interstitials is cancelled by the action of $\text{MoO}_4^{2-}$ ions [6, 48, 70]. Besides, $\text{Mo}^{4+}$ and $\text{Mo}^{6+}$ cause excessive positive charge, reducing the concentration of positive donors to satisfy the charge neutrality in the film [48].

### 3.2.3. Alloy 33 and Alloy 31

The Mott-Schottky plots of the highly alloyed austenitic stainless steels Alloy 33 and Alloy 31 (Figure 2a) reveal the existence of a very clear $n$-type region with very low capacitance values, and a less marked $p$-type region, which completely disappears in the case of Alloy 31, in spite of the high Cr content of both alloys. Therefore, the considerable increase in Cr and Ni content in Alloy 33 and Alloy 31 visibly enhances the $n$-type semiconductivity but makes the $p$-type region difficult to discern, especially for Alloy 31.

It has been commented above that Ni has not been found in the passive film of conventional austenitic stainless steels. However, if the Ni content in the alloy is high
It has been reported that high Ni stainless steels and nickel-based alloys have a much larger Ni/Fe ratio in their passive films than conventional austenitic stainless steels [8, 61, 64, 71-73]. Ni has been detected in the inner region, as well as in the intermediate and outer parts of the film [8, 61, 72, 73]. Several authors, working with highly alloyed stainless steels and nickel-base alloys, have suggested the formation of a ternary Fe-Cr-Ni oxide layer with spinel structure in the passive film [5, 64, 73]. Pourbaix diagrams for the ternary system Fe-Cr-Ni [66, 74] show that four spinel oxides can coexist in equilibrium with the aqueous solution (Fe₃O₄, NiFe₂O₄, FeCr₂O₄ and NiCr₂O₄). In a similar way to the general formula presented above for the binary Fe-Cr spinel, the general structure of the Fe-Cr-Ni spinel can be written as Ni(II)[Fe(III)ₓCr(III)₁₋ₓ]₂O₄, with 0 < y ≤ 1. In the region close to the metal surface, the spinel oxide would be rich in Cr and its properties would resemble those of NiCr₂O₄ (nickel chromite), which is a normal spinel and behaves as a p-type semiconductor [73]. As the Cr content in the passive film decreases near the outer hydroxide layer of the film, the spinel structure will change gradually from NiCr₂O₄ to NiFe₂O₄ (trevorite), which has an inverse structure and behaves as an n-type semiconductor [66, 67, 73, 75, 76]. In fact, the NiFe₂O₄ spinel is more stable than a mixture of iron oxides and/or hydroxides (Fe₃O₄, Fe₂O₃ or Fe(OH)₃) [66, 74].

According to the previous description, the Mott-Schottky plots of Alloy 33 and Alloy 31 should clearly show both a p-type and an n-type behaviour, like in the plots obtained for AISI 430, 304 and 316. Nevertheless, the Mott-Schottky plots of the high Ni austenitic stainless steels, especially Alloy 31, (Figure 2a) do not show a clear p-type region. This fact can be explained by the influence of film formation potential on the
stability of the different spinel oxides, which has not been considered in the description given above. Although the NiCr$_2$O$_4$ spinel can be an equilibrium solid phase [66, 74], its stability field is often limited at high potentials [66].

In order to study the influence of the film formation potential on the semiconducting properties of Alloys 33 and 31, the Mott-Schottky plots of the passive films formed on these two alloys at two passive potentials (low passive potential, -300 mV, and high passive potential, 100 mV) are shown in Figure 2c. The $p$-type region is much more marked at 100 mV than at -300 mV. It has been reported in literature [73, 77-81] that the concentration of Cr(III) in the passive films formed on stainless steels, Ni-Cr alloys and pure Cr increases with increasing formation potential within the passive region.

In a recent study [22] it has been determined that there is a preponderance of cation vacancies over cation interstitials and oxygen vacancies in the passive films formed on Alloy 31 in a heavy brine LiBr solution (700 g/l). In fact, the slight or nonexistent $p$-type behaviour obtained for Alloy 33 and Alloy 31 at -300 mV (Figures 2b and 2c) indicates that there is a high deficiency of cations in the region close to the metal surface and the spinel oxide in that region behaves as a highly degenerate semiconductor. Therefore, due to the high concentration of cation vacancies the spinel oxide no longer behaves as a $p$-type semiconductor but as a metal-like conductor. Thus, the presence of the $p$-type region in the Mott-Schottky plots shown in Figure 2c at the formation potential of 100 mV is probably related to the increase in Cr(III), which implies a decrease in the number of cation vacancies, $V_{Cr^{3+}}$, and the formation of the spinel NiCr$_2$O$_4$ near the metal surface, which displays $p$-type semiconductivity [73].
For Alloy 33, the donor density $N_D$ decreases significantly compared with the conventional ferritic and austenitic stainless steels used in this work (Table 3), whereas there is an increase in the value of $N_A$ (cation vacancy density cannot be determined for Alloy 31, since at -300 mV the passive film does not show $p$-type semiconducting behaviour). At 100 mV, it can be observed that $N_D$ for Alloys 33 and 31 remains approximately constant, while $N_A$ decreases significantly. This decrease is a consequence of an increase in the concentration of Cr(III) oxide within the passive film, which in turn leads to a decrease in the number of cation vacancies, $V_{Cr}^{3+}$, as explained above.

Concerning the influence of Mo at concentrations higher than 5 wt.%, it can be observed in Figures 2a and 2c that capacitance values in the $n$-type region are lower for Alloy 31 than for Alloy 33, indicating a thicker and more protective passive film. Thus, the lowest value of $N_D$ obtained for Alloy 31 (Table 3) can be related to the effect of Mo species. As it has been explained above for AISI 316, the decrease in $N_D$ is related to the presence of MoO$_4^{2-}$, Mo$^{4+}$ and Mo$^{6+}$, which neutralise or inhibit the formation of the positive donors (oxygen vacancies and/or metal interstitials). Other authors [82] suggest that Mo(VI) species, when present in the film, electrostatically interact with negatively charged cation vacancies to reduce their flux from the film/solution interface to the metal/film interface, making the condensation of vacancies more difficult.

On the other hand, some authors have associated the absence of $p$-type semiconductivity of passive films formed on high Mo stainless steels with the formation of Mo compounds in the inner layer of the passive film, such as MoO$_3$ [20, 83] which acts as an $n$-type semiconductor [20, 63].
According to the obtained results, the inner layer of the passive films formed on Alloys 33 and 31 at low passive potentials shows slight or non-existent $p$-type semiconductivity due to the formation of a highly defective Fe-Cr-Ni spinel with a large concentration of cation vacancies ($V_{Cr}^{3+}$) and $n$-type semiconductivity due to the formation of an anhydrous mixed Fe-Cr-Ni spinel oxide enriched in Fe. At high passive potentials, the inner layer of the film displays $p$-$n$ semiconductivity, the $p$-type semiconductivity being associated with the Cr-enriched Fe-Cr-Ni spinel formed near the metal surface and the $n$-type behaviour with the Fe-enriched Fe-Cr-Ni spinel formed near the outer layer of the film. The outer layer of the passive film, which exhibits $n$-type semiconductivity too, consists of a mixture of Cr and Fe hydroxides and oxy-hydroxides, as in the case of AISI 430, 304 and 316. Mo species can also be present in the passive film formed on Alloy 31.

A summary of the composition and electronic structure of the passive films formed on the different stainless steels is shown schematically in Figure 3. In AISI 316 and Alloy 31, Mo species can also be present in the passive films. Note that the different layers are not in scale.

**CONCLUSIONS**

The pitting potential was found to increase dramatically with chromium contents $> 17$ wt%, whereas molybdenum is effective at minor concentrations of 2-6 wt%. Ni does not have a significant influence on the passive behaviour of stainless steels, but reduces the passive current density of AISI 304 when compared with AISI 430.
Capacitance results indicate that the passive film formed on AISI 430 and AISI 304 consists of an inner layer of anhydrous mixed Fe-Cr oxide with a spinel structure which behaves as a $p$-type semiconductor (enriched in Cr) in the region close to the metal surface and as an $n$-type semiconductor (enriched in Fe) in the region close to the outer layer of the film, which is in turn made up of Cr and Fe hydroxides, oxy-hydroxides and Fe$_2$O$_3$ with $n$-type semiconducting behaviour. The presence of 2.3 wt.% Mo does not modify the electronic structure of the passive film formed on AISI 316, but decreases capacitance values.

The slight or non-existent $p$-type behaviour of the passive films formed on high Ni austenitic stainless steels (Alloy 33 and Alloy 31) at low passive potentials indicates that there is a high deficiency of cations in the region close to the metal surface. Therefore, the oxide spinel in that region behaves as a highly degenerate semiconductor and starts to act as a metal-like conductor. At higher passive potentials, there is an increase in Cr(III) in the passive film, resulting in a decrease in the number of cation vacancies, $V_{Cr}^{3+}$, and the formation of the spinel NiCr$_2$O$_4$ near the metal surface, which displays $p$-type semiconductivity.

A decrease in $N_D$ has been observed in presence of Mo (AISI 316 and Alloy 31), which can be related to the presence of MoO$_4^{2-}$, Mo$^{4+}$ and Mo$^{6+}$. These species neutralise or inhibit the formation of the positive donors (oxygen vacancies and/or metal interstitials).

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Tables captions

Table 1. Compositions of the different steels used in this study (in wt.%).

Table 2. Values of the pitting potential, $E_p$, and the PREN for the six steels studied in this work.

Table 3. Acceptor and donor densities for the six steels in the 992 g/l LiBr solution at 25 °C, at film formation potentials of -300 mV$_{Ag/AgCl}$ and 100 mV$_{Ag/AgCl}$.

Figures captions

Figure 1. Potentiodynamic polarisation curves for the six steels studied in the 992 g/l LiBr solution at 25° C.
Figure 2. (a) Mott-Schottky plots for the films formed on the six steels at the passive potential of -300 mV \( \text{Ag/AgCl} \); (b) Mott-Schottky plots for the films formed on the steels with lower alloy element content (carbon steel, AISI 430, AISI 304 and AISI 316) at the same passive potential; (c) comparison between Mott-Schottky plots for the passive films formed on Alloy 33 and Alloy 31 at -300 mV \( \text{Ag/AgCl} \) and at 100 mV \( \text{Ag/AgCl} \).

Figure 3. Schematic representation of the composition and electronic structure of the passive films formed on: (a) AISI 430, AISI 304 and AISI 316 at potentials within the passive range, (b) Alloy 33 and Alloy 31 at low passive potentials and (c) Alloy 33 and Alloy 31 at high passive potentials. For AISI 316 and Alloy 31, Mo species will also be present in the passive films. Note that the different layers are not in scale.
<table>
<thead>
<tr>
<th>Steel</th>
<th>Description</th>
<th>C</th>
<th>Cr</th>
<th>Ni</th>
<th>Mo</th>
<th>Si</th>
<th>P</th>
<th>Cu</th>
<th>N</th>
<th>S</th>
<th>Fe</th>
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<tbody>
<tr>
<td>S355J2G3</td>
<td>Carbon Steel</td>
<td>0.24</td>
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<tr>
<td>AISI 430</td>
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<td>17</td>
<td>----</td>
<td>&lt; 1</td>
<td>&lt; 0.04</td>
<td>-----</td>
<td>-----</td>
<td>&lt; 0.03</td>
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<tr>
<td>AISI 304</td>
<td>Austenitic SS</td>
<td>0.05</td>
<td>18</td>
<td>&lt; 0.8</td>
<td>-----</td>
<td>-----</td>
<td>0.1</td>
<td>-----</td>
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<td>------</td>
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</tr>
<tr>
<td>AISI 316</td>
<td>Austenitic SS</td>
<td>0.05</td>
<td>17</td>
<td>&lt; 0.8</td>
<td>-----</td>
<td>-----</td>
<td>0.1</td>
<td>&lt; 0.03</td>
<td></td>
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<tr>
<td>Alloy 33</td>
<td>Superaustenitic SS</td>
<td>0.015</td>
<td>32.8</td>
<td>30.9</td>
<td>1.7</td>
<td>0.3</td>
<td>0.01</td>
<td>0.6</td>
<td>0.4</td>
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</tr>
<tr>
<td>Alloy 31</td>
<td>Superaustenitic SS</td>
<td>0.015</td>
<td>26.7</td>
<td>31.8</td>
<td>6.6</td>
<td>0.1</td>
<td>0.02</td>
<td>1.2</td>
<td>0.2</td>
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<td>(UNS N08031)</td>
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Table 1
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<tr>
<th>Steel</th>
<th>PREN</th>
<th>$E_p$ (Ag/AgCl)/mV</th>
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</thead>
<tbody>
<tr>
<td>S355J2G3</td>
<td>0</td>
<td>-190 ± 9</td>
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<tr>
<td>AISI 430</td>
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<td>204 ± 26</td>
</tr>
<tr>
<td>AISI 304</td>
<td>21</td>
<td>264 ± 8</td>
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<tr>
<td>AISI 316</td>
<td>27.59</td>
<td>394 ± 23</td>
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<tr>
<td>Alloy 33</td>
<td>50.41</td>
<td>482 ± 15</td>
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<tr>
<td>Alloy 31</td>
<td>54.48</td>
<td>533 ± 11</td>
</tr>
<tr>
<td>Steel</td>
<td>-300 mV</td>
<td>100 mV</td>
</tr>
<tr>
<td>--------------</td>
<td>---------</td>
<td>--------</td>
</tr>
<tr>
<td></td>
<td>$N_D / 10^{20}$ cm$^{-3}$</td>
<td>$N_A / 10^{20}$ cm$^{-3}$</td>
</tr>
<tr>
<td>S355J2G3</td>
<td>21.1 ± 0.6</td>
<td>-----</td>
</tr>
<tr>
<td>AISI 430</td>
<td>11.3 ± 0.4</td>
<td>21 ± 2</td>
</tr>
<tr>
<td>AISI 304</td>
<td>11.3 ± 0.2</td>
<td>24 ± 4</td>
</tr>
<tr>
<td>AISI 316</td>
<td>9.6 ± 0.3</td>
<td>22 ± 4</td>
</tr>
<tr>
<td>Alloy 33</td>
<td>6.2 ± 0.4</td>
<td>29 ± 5</td>
</tr>
<tr>
<td>Alloy 31</td>
<td>4.5 ± 0.2</td>
<td>-----</td>
</tr>
</tbody>
</table>
Figure 1
Click here to download Figures (if any): Figure 1.doc
Figure 2

Click here to download Figures (if any): Figure 2.doc
The diagram shows the relationship between capacitance squared ($C^2$) and voltage ($E$) for different alloys at two different potentials: -300 mV and 100 mV. The graph is divided into two regions labeled as $p$-type semiconductivity and $n$-type semiconductivity.

- **Alloy 33 (-300 mV)**
- **Alloy 33 (100 mV)**
- **Alloy 31 (-300 mV)**
- **Alloy 31 (100 mV)**

The graph illustrates how the capacitance changes with voltage for each of these alloys, demonstrating the differences in their electrical properties. The $p$-type and $n$-type labels indicate the type of semiconductor behavior observed at different potentials.
Fe and Cr hydroxides, oxy-hydroxides and Fe$_2$O$_3$

Fe(II)[Cr(III)$_x$Fe(III)$_{1-x}$]$_2$O$_4$ (enriched in Fe)

Fe(II)[Cr(III)$_x$Fe(III)$_{1-x}$]$_2$O$_4$ (enriched in Cr)

Ni(II)[Fe(III)$_y$Cr(III)$_{1-y}$]$_2$O$_4$ (enriched in Fe)

Ni(II)[Fe(III)$_y$Cr(III)$_{1-y}$]$_2$O$_4$ (very high V$_{Cr^{3+}}$ density)

Fe and Cr hydroxides, oxy-hydroxides and Fe$_2$O$_3$

Fe(II)[Cr(III)$_x$Fe(III)$_{1-x}$]$_2$O$_4$ (enriched in Cr)

Fe(II)[Cr(III)$_x$Fe(III)$_{1-x}$]$_2$O$_4$ (enriched in Fe)

Ni(II)[Fe(III)$_y$Cr(III)$_{1-y}$]$_2$O$_4$ (enriched in Fe)

Ni(II)[Fe(III)$_y$Cr(III)$_{1-y}$]$_2$O$_4$ (very high V$_{Cr^{3+}}$ density)